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Noise of Sources

INTRODUCTION

The elimination or minimization of noise is one of the most perplexing problems facing engineers today. Many preamplifiers and components come with outstanding noise specifications, only to disappoint the user. The problem is the difference between specification and application, as the amplifiers are specified under ideal conditions not the real conditions, (i.e., a transducer connected to the input). Many times the transducer noise is as large, or even greater than, the amplifier noise degrading the signal to noise ratio. Before amplifier or component noise can be considered, familiarity with the source noise is essential.

REVIEW OF NOISE BASICS

There are 3 types of transducers: resistive, capacitive and inductive. The noise of a passive network is thermal noise, generated by the real part of the complex impedance, as given by Nyquist's relation:

$$V_n^2 = 4kT\text{Re}(Z) \Delta f \quad (1)$$

Where:

$$V_n^2 = \text{Mean square noise voltage (V}^2\text{)}$$

$$k = \text{Boltzmann's constant (1.38x10}^{-23} \text{ VAS/}^\circ\text{K)}$$

$$T = \text{Absolute temperature (}^\circ\text{K)}$$

$$\text{Re}(Z) = \text{Real part of complex impedance (}\Omega\text{)}$$

$$\Delta f = \text{Noise bandwidth (Hz)}$$

The noise may be represented as a spectral density of (V^2/Hz) or more commonly in $\mu\text{V}/\sqrt{\text{Hz}}$ or $\text{nV}/\sqrt{\text{Hz}}$ and is given by:

$$e_n^2 = \frac{V_n^2}{\Delta f} \quad (2)$$

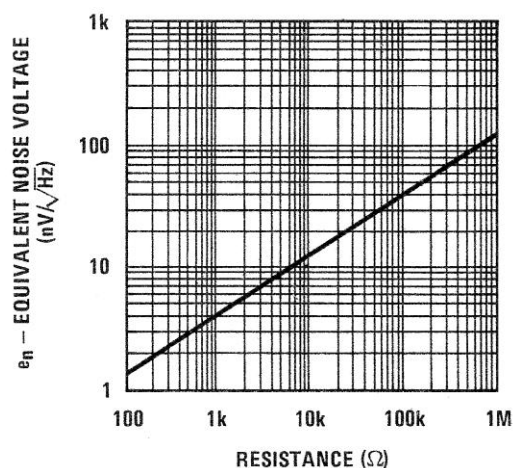


Figure 1. Thermal Noise Voltage vs. Resistance

The total noise voltage in a frequency band can be readily calculated if it is white noise (i.e., $\text{Re}(Z)$ is frequency independent). This is not the case for capacitive or inductive sources or most real world noise problems.

Rapidly changing network impedance and amplifier gain equalization combine to complicate the issue. The total source noise in a non-ideal case can be calculated by breaking the noise spectrum into several small bands where the noise ($\text{Re}(Z)$) is nearly white and calculating the noise of each band. The total source noise is the RMS sum of the noise in each of the bands N_1 - N_n .

$$V_{\text{NOISE}} = (V_{N1}^2 + V_{N2}^2 + \dots + V_{Nn}^2)^{1/2} \quad (3)$$

The expression does not take amplifier gain equalization (like RIAA) into account, which will change the character of the noise at the amplifier output. By reflecting the gain equalization to the amplifier input and normalizing the gain to 0 dB at 1 kHz, the equalized source noise may then be calculated.

$$V_{EQ} = (|A_1|^2 V_{N_1}^2 + |A_2|^2 V_{N_2}^2 + \dots + |A_n|^2 V_{N_n}^2)^{1/2} \quad (4)$$

Where V_{EQ} = equalized source noise (μV) and $|A_n|$ = magnitude of the equalized gain at the center of each noise band (V/V).

SOURCE NOISE

Models are needed for capacitive and inductive systems such that noise calculations can be made. Namely, the real part of the impedance needs to be determined.

A lumped model of a capacitive source, such as condenser or electret microphone, consists of the microphone and stray capacitance shunted by a load resistance.

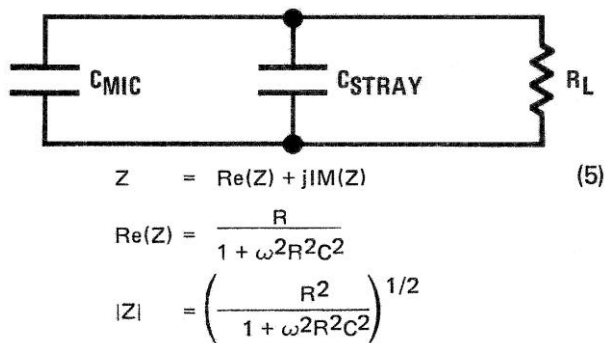


Figure 2. Lumped Model of a Capacitive Microphone

It should be noted that for any particular microphone, the noise of the network $((C_m + C_s)/R_L)$ is reduced by increasing R_L because $\text{Re}(Z)$ (the real part of the impedance) is inversely proportional to R_L (see equation 5).

The inductive source (phono cartridges and tape heads) is more complex to analyze because it has a much more complex model. The simplified lumped model of a phono cartridge or tape head consists of a series inductance and resistance shunted by a small capacitor. Each phono cartridge or tape head has a recommended load consisting of a specified shunt resistance and capacitance. A model for the inductive source and preamp input network is shown in Figure 3.

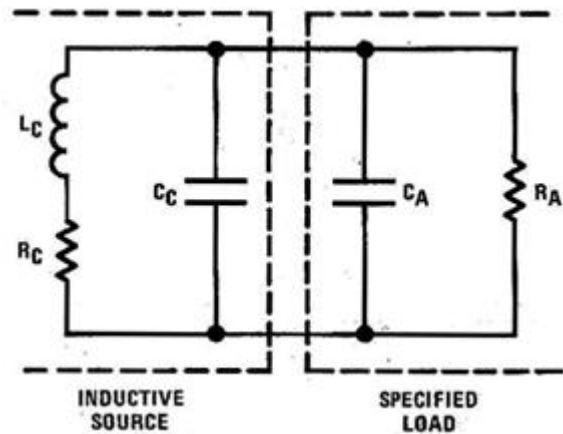
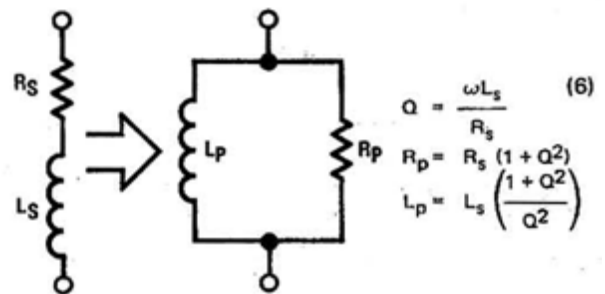


Figure 3. Phono Cartridge or Tape Head and Preamp Input Network

This circuit is quite formidable to analyze and needs, further simplification. Through the use of Q equations, a series L-R is transformed to a parallel L-R.



Simplifying the input network to:

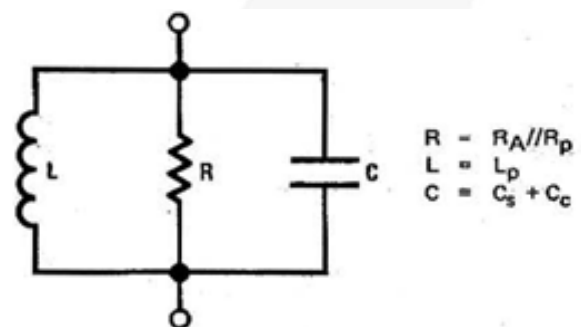


Figure 4. Simplified Inductive Source Network.

$$\begin{aligned} \text{Re}(Z) &= \frac{RX_L^2 X_C^2}{(RX_L - RX_C)^2 + X_L^2 X_C^2} \quad (7) \\ Z &= \frac{RX_L X_C}{((RX_L - RX_C)^2 + X_L^2 X_C^2)^{1/2}} \\ X_L &= \omega L \\ X_C &= 1/\omega C \end{aligned}$$

The tools are now available to calculate the noise of a variety of transducers and see how this unspecified noise affects amplifier (S/N) performance.

EXAMPLES

Calculations of electret microphone noise with various loads and RIAA equalized phono cartridge noise is done using equations (1)–(7). Center frequencies and frequency bands must be chosen first. Values of the lumped circuit components calculated and noise calculated for each band, then summed for the total noise. Octave bandwidths starting at 25 Hz will be adequate for approximating the noise.

In this example, the microphone capacitance is 10 pF loaded with 5 pF of amplifier and stray capacitance. Two resistive loads will be used to illustrate the effect R_L has on the microphone noise. $R_{L1} = 1 \text{ G}\Omega$ (10^9), $R_{L2} = 10 \text{ G}\Omega$ (10^{10}). It is assumed that there is no gain equalization in the amplifiers that follow. The noise calculations are summarized in Table I.

The electret or condenser microphone noise ($\text{Re}(Z)$) is reduced when the load resistance is increased. This is one of the cases when a larger resistance means lower noise, not more noise.

The second example is the calculation of the RIAA equalized noise of an ADC 27 phono cartridge loaded with $C_A = 250 \text{ pF}$ and $R_A = 47 \text{ k}$. The cartridge constants are $R_s = 1.13 \text{ k}$ and $L_s = 0.75 \text{ H}$ (C_c may be neglected). The noise calculations are summarized in Table II for this example.

The RIAA equalized noise of the ADC 27 phono cartridge and preamp input network was $0.73 \mu\text{V}$ for the audio band. Typical high quality preamps have noise voltages less than $1 \mu\text{V}_v$ resulting in a 3 dB or more loss in system S/N ratio when the cartridge noise is added to the preamp noise (in an RMS fashion).

CONCLUSIONS

Zero noise sources and amplifiers do not exist. Specifying amplifier noise under ideal conditions will only lead to ideal specifications, not a measure of actual performance. Methods of S/N ratio measurement should be used that reflect the true performance instead of hollow specifications.

TABLE I. Summary of Electret Microphone Calculations

f Range (Hz)	25–50	50–100	100–200	200–400	400–800	800–1600	1600–3200	3200–6400	9600–12.8k	12.8k–20k
f Center (Hz)	37.5	75	150	300	600	1200	2400	4800	9600	16,400
f _{BW} (Hz)	25	50	100	200	400	800	1600	3200	6400	7,200
for R _L = 1GΩ										
Re(Z) (Ω)	74.2M	19.6M	4.98M	1.25M	0.31M	78k	19k	4.9k	1.22k	420
Z (Ω)	272M	140M	70.6M	35.4M	17.7M	8.8M	4.4M	2.2M	1.1M	650
e _{nz} (nV/√Hz)	1100	560	280	140	71	36	18	9	4.5	2.8
V _{nz} (μV)	5.5	3.96	2.8	1.98	1.42	1.02	0.72	0.51	0.36	0.24
V _{nz} ² (μV ²)	30.2	15.7	7.84	3.92	2.0	1.04	0.52	0.26	0.13	0.06
(ΣV _{nz} ²) ^{1/2} ≈ 7.9 μV										
R _L = 10GΩ										
Re(Z) (Ω)	8M	2M	0.5M	125k	31.3k	7.8k	2k	500	122	42
Z (Ω)	283M	141M	70.8M	35.4M	17.7M	8.8M	4.4M	2.2M	1.1M	650k
e _{nz} (nV/√Hz)	320	180	90	45	23	11.4	5.8	2.9	1.4	0.84
V _{nz} (μV)	1.6	1.3	0.9	0.64	0.46	0.32	0.232	0.16	0.112	0.07
V _{nz} ² (μV ²)	2.56	1.62	0.81	0.41	0.21	0.103	0.054	0.025	0.013	0.005
(ΣV _{nz} ²) ^{1/2} ≈ 2.4 μV										

TABLE II. Summary of Phono Cartridge Calculations

f Range (Hz)	25–50	50–100	100–200	200–400	400–800	800–1.6k	1.6k–3.2k	3.2k–6.4k	6.4k–12.8k	12.8k–20k
f Center (Hz)	37.5	75	150	300	600	1200	2400	4800	9600	16.4k
f _{BW} (Hz)	25	50	100	200	400	800	1600	3200	6400	7.2k
Q = (ωL _s /R _s)	0.156	0.313	0.625	1.25	2.5	5	10	20	40	68.4
Q ²	0.0244	0.098	0.391	1.56	6.25	25	100	400	1600	4678.6
1 + Q ²	1.0244	1.098	1.391	2.56	7.25	26	101	401	1601	4679.6
1 + Q ² /Q ²	42	11.24	3.56	1.64	1.16	1.04	1.01	1.0	1.0	1.0
R _p (Ω)	1.16k	1.24k	1.57k	2.9k	8.2k	29.4k	114k	454k	1.8M	5.29M
L _p (H)	31.5	8.43	2.67	1.23	0.87	0.78	0.76	0.75	0.75	0.75
R _p /R (Ω)	1.13k	1.21k	1.52k	2.74k	7k	18.1k	32.9k	42.6k	45.8k	46.6k
X _L (Ω)	7.42k	3.97k	2.52k	2.32k	3.28k	5.88k	11.45k	22.6k	45.2k	77.2k
X _C (Ω)	17M	8.48M	4.24M	2.12M	1.06M	0.53M	0.265M	0.133M	66.3k	38.8k
Re(Z) (Ω)	1.11k	1.11k	1.11k	1.15k	1.26k	1.73k	3.86k	12.4k	41.5k	34k
Z (Ω)	1.12k	1.15k	1.3k	1.77k	2.97k	5.59k	11.7k	24.4k	43.6k	40.1k
e _{nz} (nV/√Hz)	4.24	4.24	4.24	4.31	4.51	5.29	7.9	14.2	26	23.5
V _N (nV)	21.2	30	42.4	61	90.2	149.6	316	803	2080	1994
V _N ² (nV ²)	449.4	900	1798	3721	8136	22.4k	99.9k	645k	4.33M	3.98M
A _n ²	63.0	29.5	10.7	3.85	1.66	0.85	0.49	0.154	0.043	0.019
A ² V _N ² (nV ²)	28.3k	26.6k	19.2k	13.2k	13.5k	19k	48.9k	99.3k	186k	76k

$$(\Sigma V_n^2)^{1/2} = 3 \mu V \text{ unequalized noise}$$

$$(\Sigma 1A_n^2 V_n^2)^{1/2} = 0.73 \mu V \text{ RIAA equalized noise}$$

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